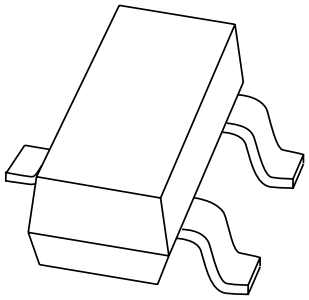
DATA SHEET



BCX19; BCX20
NPN general purpose transistors

Product specification
Supersedes data of September 1994
File under Discrete Semiconductors, SC04

1997 Mar 04

Philips
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NPN general purpose transistors BCX19; BCX20

FEATURES

- High current (500 mA)
- Low voltage (45 V).

APPLICATIONS

- General purpose amplification
- Saturated switching and driver applications.

DESCRIPTION

NPN transistor in a SOT23 plastic package.
PNP complements: BCX17 and BCX18.

MARKING

TYPE NUMBER	MARKING CODE
BCX19	U1p
BCX20	U2p

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector

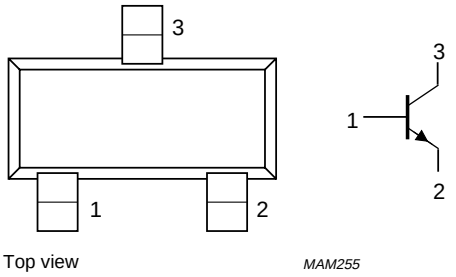


Fig.1 Simplified outline (SOT23) and symbol.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter			
	BCX19		–	50	V
	BCX20		–	30	V
V_{CEO}	collector-emitter voltage	open base			
	BCX19		–	45	V
	BCX20		–	25	V
I_{CM}	peak collector current		–	1	A
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C	–	250	mW
h_{FE}	DC current gain	I_C = 100 mA; V_{CE} = 1 V	100	600	
f_T	transition frequency	I_C = 10 mA; V_{CE} = 5 V; f = 100 MHz	100	–	MHz

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter			
	BCX19		–	50	V
	BCX20		–	30	V
V_{CEO}	collector-emitter voltage	open base; I_C = 10 mA			
	BCX19		–	45	V
	BCX20		–	25	V
V_{EBO}	emitter-base voltage	open collector	–	5	V
I_C	collector current (DC)		–	500	mA
I_{CM}	peak collector current		–	1	A
I_{BM}	peak base current		–	200	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C; note 1	–	250	mW
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C
T_{amb}	operating ambient temperature		–65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-}a}$	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

T_j = 25 °C unless otherwise specified.

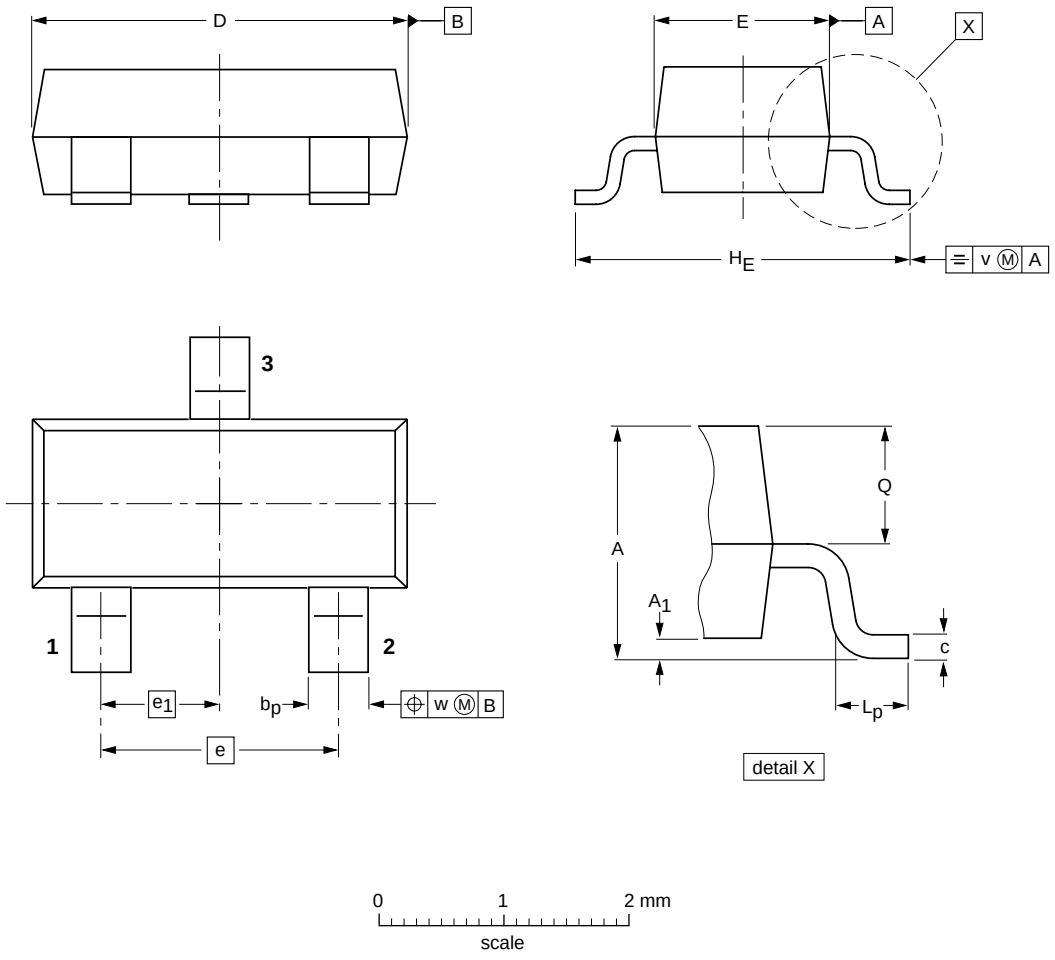
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{CBO}	collector cut-off current	I_E = 0; V_{CB} = 20 V	–	–	100	nA
		I_E = 0; V_{CB} = 20 V; T_j = 150 °C	–	–	5	µA
I_{EBO}	emitter cut-off current	I_C = 0; V_{EB} = 5 V	–	–	100	nA
h_{FE}	DC current gain	V_{CE} = 1 V; note 1				
		I_C = 100 mA	100	–	600	
		I_C = 300 mA	70	–	–	
		I_C = 500 mA	40	–	–	
V_{CEsat}	collector-emitter saturation voltage	I_C = 500 mA; I_B = 50 mA; note 2	–	–	620	mV
V_{BE}	base-emitter voltage	I_C = 500 mA; V_{CE} = 1 V; notes 1 and 2	–	–	1.2	V
C_c	collector capacitance	I_E = I_e = 0; V_{CB} = 10 V; f = 1 MHz	–	5	–	pF
f_T	transition frequency	I_C = 10 mA; V_{CE} = 5 V; f = 100 MHz	100	–	–	MHz

Notes

1. Pulse test: $t_p \leq 300$ µs; $\delta \leq 0.02$.
2. V_{BE} decreases by approximately −2 mV/°C with increasing temperature.

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads **SOT23**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1 max.	b_p	c	D	E	e	e_1	H_E	L_p	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT23						97-02-28

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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